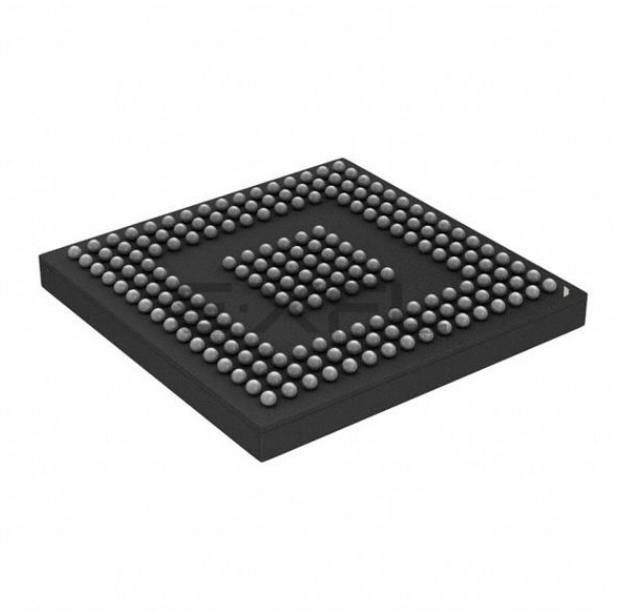

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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I²C, IrDA, LINbus, MMC/SD/SDIO, QSPI, SmartCard, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	144
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 16x12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	192-VFBGA
Supplier Device Package	192-BGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32gg11b840f1024gl192-a

3. System Overview

3.1 Introduction

The Giant Gecko Series 1 product family is well suited for any battery operated application as well as other systems requiring high performance and low energy consumption. This section gives a short introduction to the MCU system. The detailed functional description can be found in the Giant Gecko Series 1 Reference Manual.

A block diagram of the Giant Gecko Series 1 family is shown in Figure 3.1 Detailed EFM32GG11 Block Diagram on page 11. The diagram shows a superset of features available on the family, which vary by OPN. For more information about specific device features, consult Ordering Information.

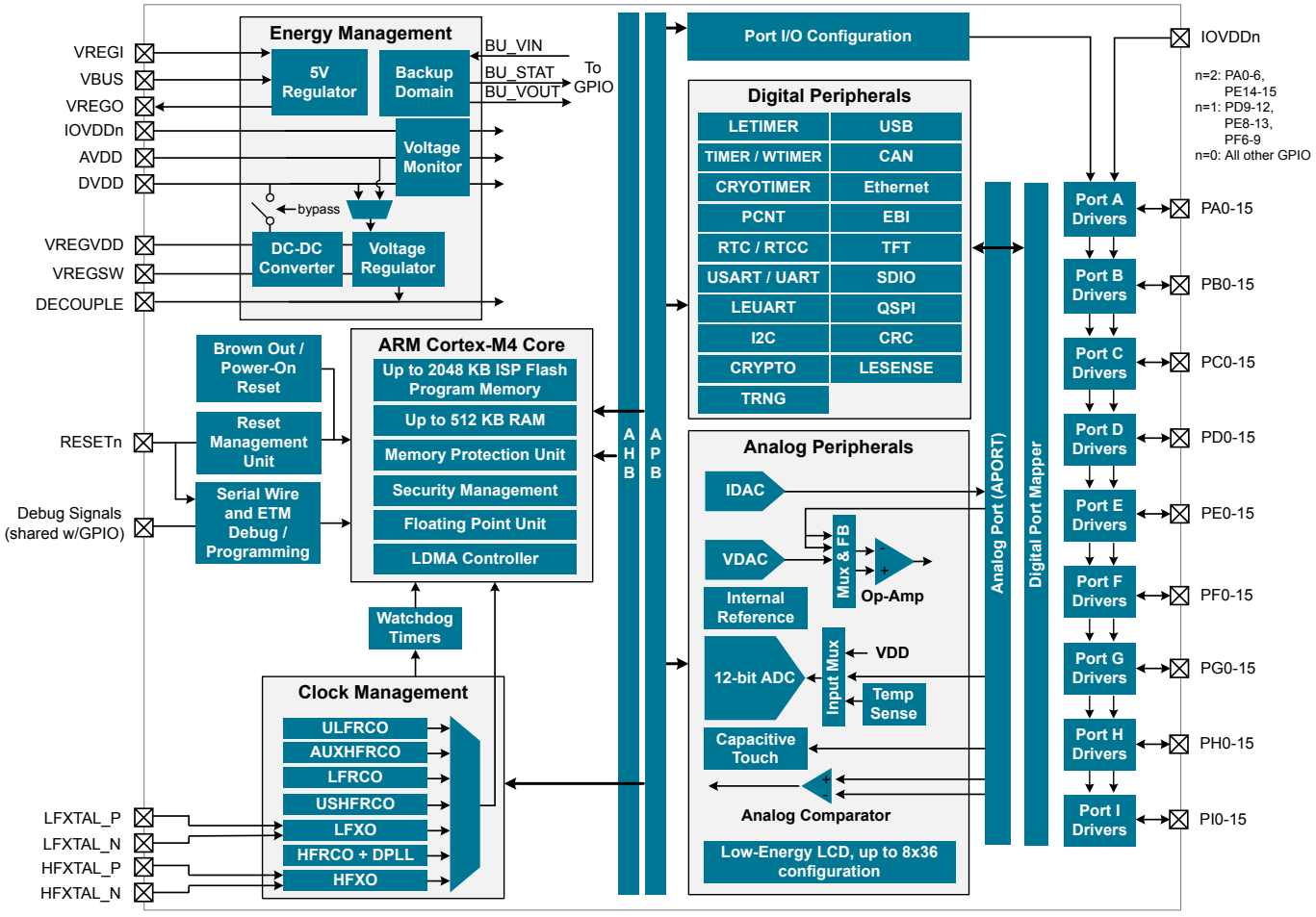

Figure 3.1. Detailed EFM32GG11 Block Diagram

3.5.6 Pulse Counter (PCNT)

The Pulse Counter (PCNT) peripheral can be used for counting pulses on a single input or to decode quadrature encoded inputs. The clock for PCNT is selectable from either an external source on pin PCTNn_S0IN or from an internal timing reference, selectable from among any of the internal oscillators, except the AUXHFRCO. The module may operate in energy mode EM0 Active, EM1 Sleep, EM2 Deep Sleep, and EM3 Stop.

3.5.7 Watchdog Timer (WDOG)

The watchdog timer can act both as an independent watchdog or as a watchdog synchronous with the CPU clock. It has windowed monitoring capabilities, and can generate a reset or different interrupts depending on the failure mode of the system. The watchdog can also monitor autonomous systems driven by PRS.

3.6 Communications and Other Digital Peripherals

3.6.1 Universal Synchronous/Asynchronous Receiver/Transmitter (USART)

The Universal Synchronous/Asynchronous Receiver/Transmitter is a flexible serial I/O module. It supports full duplex asynchronous UART communication with hardware flow control as well as RS-485, SPI, MicroWire and 3-wire. It can also interface with devices supporting:

- ISO7816 SmartCards
- IrDA
- I^2S

3.6.2 Universal Asynchronous Receiver/Transmitter (UART)

The Universal Asynchronous Receiver/Transmitter is a subset of the USART module, supporting full duplex asynchronous UART communication with hardware flow control and RS-485.

3.6.3 Low Energy Universal Asynchronous Receiver/Transmitter (LEUART)

The unique LEUART™ provides two-way UART communication on a strict power budget. Only a 32.768 kHz clock is needed to allow UART communication up to 9600 baud. The LEUART includes all necessary hardware to make asynchronous serial communication possible with a minimum of software intervention and energy consumption.

3.6.4 Inter-Integrated Circuit Interface (I^2C)

The I^2C module provides an interface between the MCU and a serial I^2C bus. It is capable of acting as both a master and a slave and supports multi-master buses. Standard-mode, fast-mode and fast-mode plus speeds are supported, allowing transmission rates from 10 kbit/s up to 1 Mbit/s. Slave arbitration and timeouts are also available, allowing implementation of an SMBus-compliant system. The interface provided to software by the I^2C module allows precise timing control of the transmission process and highly automated transfers. Automatic recognition of slave addresses is provided in active and low energy modes.

3.6.5 External Bus Interface (EBI)

The External Bus Interface provides access to external parallel interface devices. The interface is memory mapped into the address bus of the Cortex-M4. This enables seamless access from software without manually manipulating the I/O settings each time a read or write is performed. The data and address lines are multiplexed in order to reduce the number of pins required to interface to external devices. Timing is adjustable to meet specifications of the external devices. The interface is limited to asynchronous devices.

The EBI contains a TFT controller which can drive a TFT via an RGB interface. The TFT controller supports programmable display and port sizes and offers accurate control of frequency and setup and hold timing. Direct Drive is supported for TFT displays which do not have their own frame buffer. In that case TFT Direct Drive can transfer data from either on-chip memory or from an external memory device to the TFT at low CPU load. Automatic alpha-blending and masking is also supported for transfers through the EBI interface.

4.1.6 Backup Supply Domain

Table 4.6. Backup Supply Domain

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Backup supply voltage range	V_{BU_VIN}		1.8	—	3.8	V
PWRRES resistor	R_{PWRRES}	EMU_BUCTRL_PWRRES = RES0	3400	3900	4400	Ω
		EMU_BUCTRL_PWRRES = RES1	1450	1800	2150	Ω
		EMU_BUCTRL_PWRRES = RES2	1000	1350	1700	Ω
		EMU_BUCTRL_PWRRES = RES3	525	815	1100	Ω
Output impedance between BU_VIN and BU_VOUT [2]	R_{BU_VOUT}	EMU_BUCTRL_VOUTRES = STRONG	35	110	185	Ω
		EMU_BUCTRL_VOUTRES = MED	475	775	1075	Ω
		EMU_BUCTRL_VOUTRES = WEAK	5600	6500	7400	Ω
Supply current	I_{BU_VIN}	BU_VIN not powering backup domain	—	11	TBD	nA
		BU_VIN powering backup domain[1]	—	550	TBD	nA

Note:

1. Additional current required by backup circuitry when backup is active. Includes supply current of backup switches and backup regulator. Does not include supply current required for backed-up circuitry.
2. BU_VOUT and BU_STAT signals are not available in all package configurations. Check the device pinout for availability.

4.1.19 Operational Amplifier (OPAMP)

Unless otherwise indicated, specified conditions are: Non-inverting input configuration, VDD = 3.3 V, DRIVESTRENGTH = 2, MAINOUTEN = 1, C_{LOAD} = 75 pF with OUTSCALE = 0, or C_{LOAD} = 37.5 pF with OUTSCALE = 1. Unit gain buffer and 3X-gain connection as specified in table footnotes[8] [1].

Table 4.27. Operational Amplifier (OPAMP)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Supply voltage (from AVDD)	V_{OPA}	HCMDIS = 0, Rail-to-rail input range	2	—	3.8	V
		HCMDIS = 1	1.62	—	3.8	V
Input voltage	V_{IN}	HCMDIS = 0, Rail-to-rail input range	V_{VSS}	—	V_{OPA}	V
		HCMDIS = 1	V_{VSS}	—	V_{OPA}-1.2	V
Input impedance	R_{IN}		100	—	—	MΩ
Output voltage	V_{OUT}		V_{VSS}	—	V_{OPA}	V
Load capacitance[2]	C_{LOAD}	OUTSCALE = 0	—	—	75	pF
		OUTSCALE = 1	—	—	37.5	pF
Output impedance	R_{OUT}	DRIVESTRENGTH = 2 or 3, 0.4 V ≤ V_{OUT} ≤ V_{OPA} - 0.4 V, -8 mA < I_{OUT} < 8 mA, Buffer connection, Full supply range	—	0.25	—	Ω
		DRIVESTRENGTH = 0 or 1, 0.4 V ≤ V_{OUT} ≤ V_{OPA} - 0.4 V, -400 µA < I_{OUT} < 400 µA, Buffer connection, Full supply range	—	0.6	—	Ω
		DRIVESTRENGTH = 2 or 3, 0.1 V ≤ V_{OUT} ≤ V_{OPA} - 0.1 V, -2 mA < I_{OUT} < 2 mA, Buffer connection, Full supply range	—	0.4	—	Ω
		DRIVESTRENGTH = 0 or 1, 0.1 V ≤ V_{OUT} ≤ V_{OPA} - 0.1 V, -100 µA < I_{OUT} < 100 µA, Buffer connection, Full supply range	—	1	—	Ω
Internal closed-loop gain	G_{CL}	Buffer connection	TBD	1	TBD	-
		3x Gain connection	TBD	2.99	TBD	-
		16x Gain connection	TBD	15.7	TBD	-
Active current[4]	I_{OPA}	DRIVESTRENGTH = 3, OUTSCALE = 0	—	580	—	µA
		DRIVESTRENGTH = 2, OUTSCALE = 0	—	176	—	µA
		DRIVESTRENGTH = 1, OUTSCALE = 0	—	13	—	µA
		DRIVESTRENGTH = 0, OUTSCALE = 0	—	4.7	—	µA

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Open-loop gain	G_{OL}	DRIVESTRENGTH = 3	—	135	—	dB
		DRIVESTRENGTH = 2	—	137	—	dB
		DRIVESTRENGTH = 1	—	121	—	dB
		DRIVESTRENGTH = 0	—	109	—	dB
Loop unit-gain frequency[7]	UGF	DRIVESTRENGTH = 3, Buffer connection	—	3.38	—	MHz
		DRIVESTRENGTH = 2, Buffer connection	—	0.9	—	MHz
		DRIVESTRENGTH = 1, Buffer connection	—	132	—	kHz
		DRIVESTRENGTH = 0, Buffer connection	—	34	—	kHz
		DRIVESTRENGTH = 3, 3x Gain connection	—	2.57	—	MHz
		DRIVESTRENGTH = 2, 3x Gain connection	—	0.71	—	MHz
		DRIVESTRENGTH = 1, 3x Gain connection	—	113	—	kHz
		DRIVESTRENGTH = 0, 3x Gain connection	—	28	—	kHz
Phase margin	PM	DRIVESTRENGTH = 3, Buffer connection	—	67	—	°
		DRIVESTRENGTH = 2, Buffer connection	—	69	—	°
		DRIVESTRENGTH = 1, Buffer connection	—	63	—	°
		DRIVESTRENGTH = 0, Buffer connection	—	68	—	°
Output voltage noise	N_{OUT}	DRIVESTRENGTH = 3, Buffer connection, 10 Hz - 10 MHz	—	146	—	µVrms
		DRIVESTRENGTH = 2, Buffer connection, 10 Hz - 10 MHz	—	163	—	µVrms
		DRIVESTRENGTH = 1, Buffer connection, 10 Hz - 1 MHz	—	170	—	µVrms
		DRIVESTRENGTH = 0, Buffer connection, 10 Hz - 1 MHz	—	176	—	µVrms
		DRIVESTRENGTH = 3, 3x Gain connection, 10 Hz - 10 MHz	—	313	—	µVrms
		DRIVESTRENGTH = 2, 3x Gain connection, 10 Hz - 10 MHz	—	271	—	µVrms
		DRIVESTRENGTH = 1, 3x Gain connection, 10 Hz - 1 MHz	—	247	—	µVrms
		DRIVESTRENGTH = 0, 3x Gain connection, 10 Hz - 1 MHz	—	245	—	µVrms

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit

Note:

1. Specified configuration for 3X-Gain configuration is: INCBW = 1, HCMDIS = 1, RESINSEL = VSS, V_{INPUT} = 0.5 V, V_{OUTPUT} = 1.5 V. Nominal voltage gain is 3.
2. If the maximum C_{LOAD} is exceeded, an isolation resistor is required for stability. See AN0038 for more information.
3. When INCBW is set to 1 the OPAMP bandwidth is increased. This is allowed only when the non-inverting close-loop gain is ≥ 3, or the OPAMP may not be stable.
4. Current into the load resistor is excluded. When the OPAMP is connected with closed-loop gain > 1, there will be extra current to drive the resistor feedback network. The internal resistor feedback network has total resistance of 143.5 kOhm, which will cause another ~10 µA current when the OPAMP drives 1.5 V between output and ground.
5. Step between 0.2V and V_{OPA}-0.2V, 10%-90% rising/falling range.
6. From enable to output settled. In sample-and-off mode, RC network after OPAMP will contribute extra delay. Settling error < 1mV.
7. In unit gain connection, UGF is the gain-bandwidth product of the OPAMP. In 3x Gain connection, UGF is the gain-bandwidth product of the OPAMP and 1/3 attenuation of the feedback network.
8. Specified configuration for Unit gain buffer configuration is: INCBW = 0, HCMDIS = 0, RESINSEL = DISABLE. V_{INPUT} = 0.5 V, V_{OUTPUT} = 0.5 V.
9. When HCMDIS=1 and input common mode transitions the region from V_{OPA}-1.4V to V_{OPA}-1V, input offset will change. PSRR and CMRR specifications do not apply to this transition region.

4.1.20 LCD Driver

Table 4.28. LCD Driver

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frame rate	f_{LCDFR}		TBD	—	TBD	Hz
LCD supply range[2]	V_{LCDIN}		1.8	—	3.8	V
LCD output voltage range	V_{LCD}	Current source mode, No external LCD capacitor	2.0	—	V_{LCDIN}-0.4	V
		Step-down mode with external LCD capacitor	2.0	—	V_{LCDIN}	V
		Charge pump mode with external LCD capacitor	2.0	—	1.9 * V_{LCDIN}	V
Contrast control step size	$STEP_{CONTRAST}$	Current source mode	—	64	—	mV
		Charge pump or Step-down mode	—	43	—	mV
Contrast control step accuracy[1]	$ACC_{CONTRAST}$		—	+/-4	—	%

Note:

1. Step size accuracy is measured relative to the typical step size, and typ value represents one standard deviation.
2. V_{LCDIN} is selectable between the AVDD or DVDD supply pins, depending on EMU_PWRCTRL_ANASW.

EBI Ready/Wait Timing Requirements

Timing applies to both EBI_REn and EBI_WEn for all addressing modes and both polarities. All numbers are based on route locations 0,1,2 only (with all EBI alternate functions using the same location at the same time). Timing is specified at 10% and 90% of IOVDD, 25 pF external loading, and slew rate for all GPIO set to 6.

Table 4.41. EBI Ready/Wait Timing Requirements

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Setup time, from EBI_ARDY valid to trailing EBI_REn, EBI_WEn edge	t_{SU_ARDY}	IOVDD ≥ 1.62 V	55 + (3 * $t_{HFCOR-ECLK}$)	—	—	ns
		IOVDD ≥ 3.0 V	36 + (3 * $t_{HFCOR-ECLK}$)	—	—	ns
Hold time, from trailing EBI_REn, EBI_WEn edge to EBI_ARDY invalid	t_{H_ARDY}	IOVDD ≥ 1.62 V	-9	—	—	ns

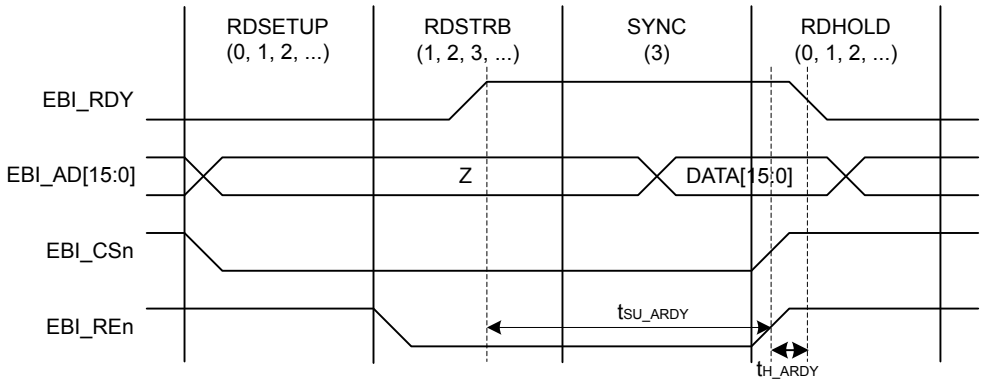

Figure 4.8. EBI Ready/Wait Timing Requirements

SDIO MMC SDR Mode Timing at 1.8 V

Timing is specified for route location 0 at 1.8 V IOVDD with voltage scaling disabled. Slew rate for SD_CLK set to 7, all other GPIO set to 6, DRIVESTRENGTH = STRONG for all pins. SDIO_CTRL_TXDLYMUXSEL = 1. Loading between 5 and 10 pF on all pins or between 10 and 20 pF on all pins.

Table 4.50. SDIO MMC SDR Mode Timing (Location 0, 1.8V I/O)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Clock frequency during data transfer	F_{SD_CLK}	Using HFRCO, AUXHFRCO, or USHFRCO	—	—	25	MHz
		Using HFXO	—	—	TBD	MHz
Clock low time	t_{WL}	Using HFRCO, AUXHFRCO, or USHFRCO	18.1	—	—	ns
		Using HFXO	TBD	—	—	ns
Clock high time	t_{WH}	Using HFRCO, AUXHFRCO, or USHFRCO	18.1	—	—	ns
		Using HFXO	TBD	—	—	ns
Clock rise time	t_R		1.96	8.27	—	ns
Clock fall time	t_F		1.67	6.90	—	ns
Input setup time, CMD, DAT[0:7] valid to SD_CLK	t_{ISU}		5.3	—	—	ns
Input hold time, SD_CLK to CMD, DAT[0:7] change	t_{IH}		2.5	—	—	ns
Output delay time, SD_CLK to CMD, DAT[0:7] valid	t_{ODLY}		0	—	16	ns
Output hold time, SD_CLK to CMD, DAT[0:7] change	t_{OH}		3	—	—	ns

5. Pin Definitions

5.1 EFM32GG11B8xx in BGA192 Device Pinout

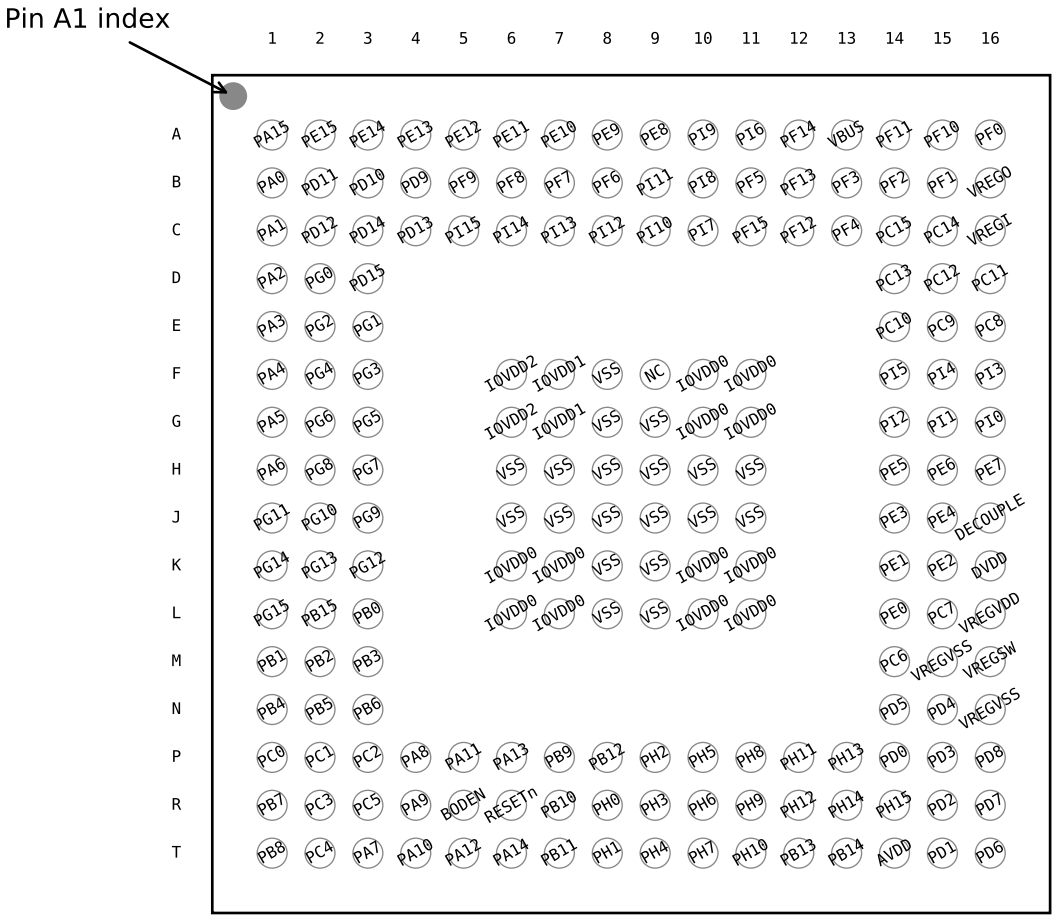

Figure 5.1. EFM32GG11B8xx in BGA192 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.20 GPIO Functionality Table or 5.21 Alternate Functionality Overview.

Table 5.1. EFM32GG11B8xx in BGA192 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA15	A1	GPIO	PE15	A2	GPIO
PE14	A3	GPIO	PE13	A4	GPIO
PE12	A5	GPIO	PE11	A6	GPIO
PE10	A7	GPIO	PE9	A8	GPIO
PE8	A9	GPIO	PI9	A10	GPIO (5V)
PI6	A11	GPIO (5V)	PF14	A12	GPIO (5V)

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB2	M2	GPIO	PB3	M3	GPIO
PC6	M14	GPIO	VREGVSS	M15 N16	Voltage regulator VSS
VREGSW	M16	DCDC regulator switching node	PB4	N1	GPIO
PB5	N2	GPIO	PB6	N3	GPIO
PD5	N14	GPIO	PD4	N15	GPIO
PC0	P1	GPIO (5V)	PC1	P2	GPIO (5V)
PC2	P3	GPIO (5V)	PA8	P4	GPIO
PA11	P5	GPIO	PA13	P6	GPIO (5V)
PB9	P7	GPIO (5V)	PB12	P8	GPIO
PH2	P9	GPIO (5V)	PH5	P10	GPIO
PH8	P11	GPIO (5V)	PH11	P12	GPIO (5V)
PH13	P13	GPIO (5V)	PD0	P14	GPIO (5V)
PD3	P15	GPIO	PD8	P16	GPIO
PB7	R1	GPIO	PC3	R2	GPIO (5V)
PC5	R3	GPIO	PA9	R4	GPIO
BODEN	R5	Brown-Out Detector Enable. This pin may be left disconnected or tied to AVDD.	RESETn	R6	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB10	R7	GPIO (5V)	PH0	R8	GPIO (5V)
PH3	R9	GPIO (5V)	PH6	R10	GPIO
PH9	R11	GPIO (5V)	PH12	R12	GPIO (5V)
PH14	R13	GPIO (5V)	PH15	R14	GPIO (5V)
PD2	R15	GPIO (5V)	PD7	R16	GPIO
PB8	T1	GPIO	PC4	T2	GPIO
PA7	T3	GPIO	PA10	T4	GPIO
PA12	T5	GPIO (5V)	PA14	T6	GPIO
PB11	T7	GPIO	PH1	T8	GPIO (5V)
PH4	T9	GPIO	PH7	T10	GPIO (5V)
PH10	T11	GPIO (5V)	PB13	T12	GPIO
PB14	T13	GPIO	AVDD	T14	Analog power supply.
PD1	T15	GPIO	PD6	T16	GPIO

Note:

1. GPIO with 5V tolerance are indicated by (5V).
2. The pins PD13, PD14, and PD15 will not be 5V tolerant on all future devices. In order to preserve upgrade options with full hardware compatibility, do not use these pins with 5V domains.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA15	B1	GPIO	PE14	B2	GPIO
PE12	B3	GPIO	PE8	B4	GPIO
PD11	B5	GPIO	PD9	B6	GPIO
PF8	B7	GPIO	PF6	B8	GPIO
PF14	B9	GPIO (5V)	PF12	B10	GPIO
PF2	B11	GPIO	PF0	B12	GPIO (5V)
PC14	B13	GPIO (5V)	VREGO	B14	Decoupling for 5 V regulator and regulator output. Power for USB PHY in USB-enabled OPNs
PA1	C1	GPIO	PA0	C2	GPIO
PD13	C3	GPIO (5V)	PE10	C4	GPIO
PI8	C5	GPIO (5V)	PI7	C6	GPIO (5V)
PI6	C7	GPIO (5V)	PF5	C8	GPIO
PF15	C9	GPIO (5V)	PF4	C10	GPIO
PF3	C11	GPIO	PC13	C12	GPIO (5V)
PC12	C13	GPIO (5V)	VREGI	C14	Input to 5 V regulator.
PA3	D1	GPIO	PA2	D2	GPIO
PD14	D3	GPIO (5V)	PC11	D12	GPIO (5V)
PC10	D13	GPIO (5V)	PC9	D14	GPIO (5V)
PA5	E1	GPIO	PA4	E2	GPIO
PD15	E3	GPIO (5V)	IOVDD1	E6	Digital IO power supply 1.
VSS	E7 E8 G5 G7 G8 G10 H5 H7 H8 H10 K7 K8	Ground	IOVDD0	E9 F10 J5 J10 K6 K9	Digital IO power supply 0.
PC8	E12	GPIO (5V)	PI5	E13	GPIO (5V)
PI4	E14	GPIO (5V)	PG0	F1	GPIO (5V)
PA6	F2	GPIO	PG1	F3	GPIO (5V)
IOVDD2	F5	Digital IO power supply 2.	PI3	F12	GPIO (5V)
PI2	F13	GPIO (5V)	PI1	F14	GPIO (5V)
PG3	G1	GPIO (5V)	PG4	G2	GPIO (5V)
PG2	G3	GPIO (5V)	PE7	G12	GPIO
PI0	G13	GPIO (5V)	DECOUPLE	G14	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PC1	K2	GPIO (5V)	PE0	K12	GPIO (5V)
VREGSW	K13	DCDC regulator switching node	PC2	L1	GPIO (5V)
PC3	L2	GPIO (5V)	PA7	L3	GPIO
PB9	L13	GPIO (5V)	PB10	L14	GPIO (5V)
PD1	L17	GPIO	PC6	L18	GPIO
PC7	L19	GPIO	VREGVSS	L20	Voltage regulator VSS
PB7	M1	GPIO	PC4	M2	GPIO
PA8	M3	GPIO	PA10	M4	GPIO
PA13	M5	GPIO (5V)	PA14	M6	GPIO
RESETn	M7	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.	PB12	M8	GPIO
PD0	M9	GPIO (5V)	PD2	M10	GPIO (5V)
PD3	M11	GPIO	PD4	M12	GPIO
PD8	M13	GPIO	PB8	N1	GPIO
PC5	N2	GPIO	PA9	N3	GPIO
PA11	N4	GPIO	PA12	N5	GPIO (5V)
PB11	N6	GPIO	BODEN	N7	Brown-Out Detector Enable. This pin may be left disconnected or tied to AVDD.
PB13	N8	GPIO	PB14	N9	GPIO
AVDD	N10	Analog power supply.	PD5	N11	GPIO
PD6	N12	GPIO	PD7	N13	GPIO

Note:

1. GPIO with 5V tolerance are indicated by (5V).
2. The pins PD13, PD14, and PD15 will not be 5V tolerant on all future devices. In order to preserve upgrade options with full hardware compatibility, do not use these pins with 5V domains.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PD15	J2	GPIO (5V)	PC6	J12	GPIO
DECOUPLE	J13	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PC0	K1	GPIO (5V)
PC1	K2	GPIO (5V)	PD8	K13	GPIO
PC2	L1	GPIO (5V)	PC3	L2	GPIO (5V)
PA7	L3	GPIO	PB9	L15	GPIO (5V)
PB10	L16	GPIO (5V)	PD0	L17	GPIO (5V)
PD1	L18	GPIO	PD4	L19	GPIO
PD7	L20	GPIO	PB7	M1	GPIO
PC4	M2	GPIO	PA8	M3	GPIO
PA10	M4	GPIO	PA13	M5	GPIO (5V)
PA14	M6	GPIO	RESETn	M7	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
AVDD	M9 M10 N11	Analog power supply.	PD3	M12	GPIO
PD6	M13	GPIO	PB8	N1	GPIO
PC5	N2	GPIO	PA9	N3	GPIO
PA11	N4	GPIO	PA12	N5	GPIO (5V)
PB11	N6	GPIO	PB12	N7	GPIO
PB13	N9	GPIO	PB14	N10	GPIO
PD2	N12	GPIO (5V)	PD5	N13	GPIO

Note:

1. GPIO with 5V tolerance are indicated by (5V).
2. The pins PD13, PD14, and PD15 will not be 5V tolerant on all future devices. In order to preserve upgrade options with full hardware compatibility, do not use these pins with 5V domains.

5.8 EFM32GG11B8xx in QFP100 Device Pinout

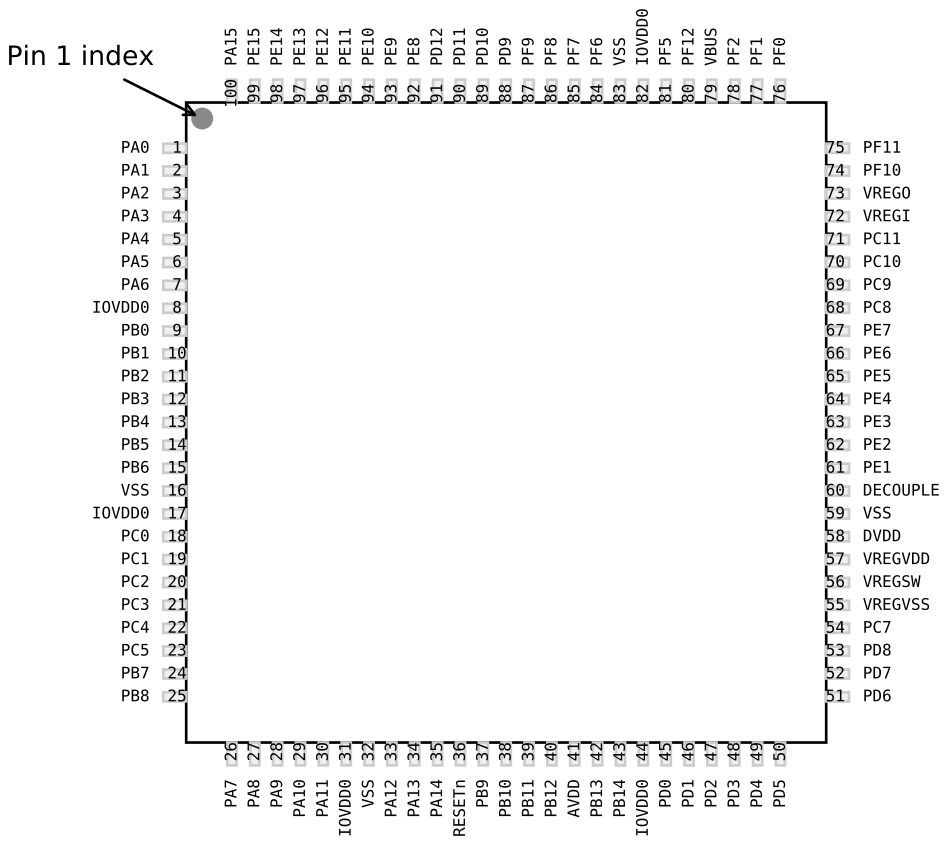

Figure 5.8. EFM32GG11B8xx in QFP100 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.20 GPIO Functionality Table or 5.21 Alternate Functionality Overview.

Table 5.8. EFM32GG11B8xx in QFP100 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	PA3	4	GPIO
PA4	5	GPIO	PA5	6	GPIO
PA6	7	GPIO	IOVDD0	8 17 31 44 82	Digital IO power supply 0.
PB0	9	GPIO	PB1	10	GPIO

5.12 EFM32GG11B8xx in QFP64 Device Pinout

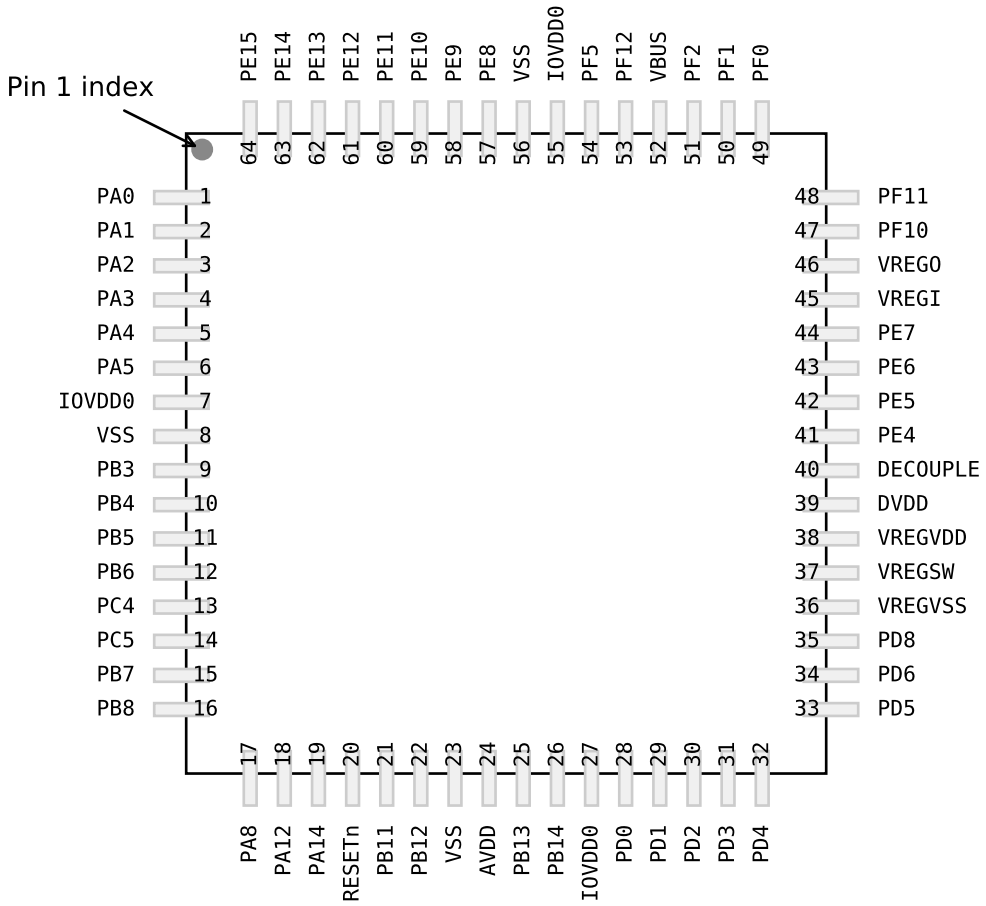

Figure 5.12. EFM32GG11B8xx in QFP64 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.20 GPIO Functionality Table or 5.21 Alternate Functionality Overview.

Table 5.12. EFM32GG11B8xx in QFP64 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	PA3	4	GPIO
PA4	5	GPIO	PA5	6	GPIO
IOVDD0	7 27 55	Digital IO power supply 0.	VSS	8 23 56	Ground
PB3	9	GPIO	PB4	10	GPIO
PB5	11	GPIO	PB6	12	GPIO

GPIO Name	Pin Alternate Functionality / Description				
	Analog	EBI	Timers	Communication	Other
PD13		EBI_ARDY #1	TIM2_CDTI0 #1 TIM3_CC1 #6 WTIM0_CC1 #1	ETH_MDIO #1 US4_CTS #1 US5_CLK #1	ETM_TD1 #1
PI15				CAN1_TX #7 US3_CS #5	
PI14				CAN1_RX #7 US3_CLK #5	
PI13				CAN0_TX #7 US3_RX #5	
PI12				CAN0_RX #7 US3_TX #5	
PI10		EBI_A15 #2	TIM4_CC2 #3	US4_CTS #3	
PI7		EBI_A12 #2	TIM1_CC1 #7 TIM4_CC2 #2 WTIM3_CC1 #5	US4_RX #3	
PF15	BUSCY BUSDX		TIM1_CC2 #6 TIM4_CC2 #1 WTIM3_CC2 #7	US5_TX #2 I2C2_SDA #5	
PF12	BUSDY BUSCX	EBI_NANDREn #5	TIM4_CC2 #0 TIM1_CC3 #5 TIM5_CC0 #7 WTIM3_CC2 #6	US5_CS #2 I2C2_SCL #3 USB_ID	
PF4	BUSDY BUSCX LCD_SEG2	EBI_WEn #0 EBI_WEn #5	TIM4_CC1 #0 TIM0_CDTI1 #2 TIM1_CC2 #5 WTIM3_CC1 #6	US1_RTS #2 I2C2_SDA #3	PRS_CH1 #1
PC15	VDAC0_OUT1ALT / OPA1_OUTALT #3 BUSACMP1Y BUSACMP1X	EBI_NANDREn #4	TIM0_CDTI2 #1 TIM1_CC2 #0 WTIM0_CC0 #4 LETIM0_OUT1 #5	US0_CLK #3 US1_CLK #3 US3_RTS #3 U0_RX #3 U1_RTS #0 LEU0_RX #5 I2C2_SCL #1	LES_CH15 PRS_CH1 #2 ACMP3_O #1 DBG_SWO #1
PC14	VDAC0_OUT1ALT / OPA1_OUTALT #2 BUSACMP1Y BUSACMP1X	EBI_NANDWEn #4	TIM0_CDTI1 #1 TIM1_CC1 #0 TIM1_CC3 #4 TIM5_CC0 #6 WTIM3_CC0 #3 LETIM0_OUT0 #5 PCNT0_S1IN #0	US0_CS #3 US1_CS #3 US2_RTS #3 US3_CS #2 U0_TX #3 U1_CTS #0 LEU0_TX #5 I2C2_SDA #1	LES_CH14 PRS_CH0 #2 ACMP3_O #2
PA2	BUSBY BUSAX LCD_SEG15	EBI_AD11 #0 EBI_DTEN #3	TIM0_CC2 #0 TIM3_CC2 #4	ETH_RMIIRXD0 #0 ETH_MIITXD2 #0 SDIO_DAT2 #1 US1_RX #6 US3_CLK #0 QSPI0_DQ0 #1	CMU_CLK0 #0 PRS_CH8 #1 ETM_TD0 #3
PG0	BUSACMP2Y BUSACMP2X	EBI_AD00 #2	TIM6_CC0 #0 TIM2_CDTI0 #3 WTIM0_CDTI1 #1 LETIM1_OUT0 #6	ETH_MIITXCLK #1 US3_TX #4 QSPI0_SCLK #2	CMU_CLK2 #3

GPIO Name	Pin Alternate Functionality / Description				
	Analog	EBI	Timers	Communication	Other
PB0	BUSBY BUSAX LCD_SEG32	EBI_AD00 #1 EBI_CS0 #3 EBI_A16 #0	TIM2_CDTI0 #0 TIM1_CC0 #2 TIM3_CC2 #7 WTIM0_CC0 #5 PCNT0_S0IN #5 PCNT1_S1IN #2	LEU1_TX #3	PRS_CH4 #1 ACMP0_O #5
PE0	BUSDY BUSCX	EBI_A00 #2 EBI_A07 #0	TIM3_CC0 #1 WTIM1_CC1 #3 PCNT0_S0IN #1	CAN0_RX #6 U0_TX #1 I2C1_SDA #2	PRS_CH22 #1 ACMP2_O #1
PC7	BUSACMP0Y BUSACMP0X OPA3_N	EBI_A06 #0 EBI_A13 #1 EBI_A21 #3	WTIM1_CC0 #3	US0_CTS #2 US1_RTS #3 LEU1_RX #0 I2C0_SCL #2	LES_CH7 PRS_CH15 #1 ETM_TD0 #2
PB1	BUSAY BUSBX LCD_SEG33	EBI_AD01 #1 EBI_CS1 #3 EBI_A17 #0	TIM2_CDTI1 #0 TIM1_CC1 #2 WTIM0_CC1 #5 LE-TIM1_OUT1 #5 PCNT0_S1IN #5	ETH_MIICRS #0 US5_RX #2 LEU1_RX #3	PRS_CH5 #1
PB2	BUSBY BUSAX LCD_SEG34	EBI_AD02 #1 EBI_CS2 #3 EBI_A18 #0	TIM2_CDTI2 #0 TIM1_CC2 #2 WTIM0_CC2 #5 LE-TIM1_OUT0 #5	ETH_MIICOL #0 US1_CS #6	PRS_CH18 #0 ACMP0_O #6
PB3	BUSAY BUSBX LCD_SEG20 / LCD_COM4	EBI_AD03 #1 EBI_CS3 #3 EBI_A19 #0	TIM1_CC3 #2 WTIM0_CC0 #6 PCNT1_S0IN #1	ETH_MIICRS #2 ETH_MDIO #0 SDIO_DAT6 #1 US2_TX #1 US3_TX #2 QSPI0_DQ4 #1	PRS_CH19 #0 ACMP0_O #7
PC6	BUSACMP0Y BUSACMP0X OPA3_P	EBI_A05 #0	WTIM1_CC3 #2	US0_RTS #2 US1_CTS #3 LEU1_TX #0 I2C0_SDA #2	LES_CH6 PRS_CH14 #1 ETM_TCLK #2
PB4	BUSBY BUSAX LCD_SEG21 / LCD_COM5	EBI_AD04 #1 EBI_ARDY #3 EBI_A20 #0	WTIM0_CC1 #6 PCNT1_S1IN #1	ETH_MIICOL #2 ETH_MDC #0 SDIO_DAT7 #1 US2_RX #1 QSPI0_DQ5 #1 LEU1_TX #4	PRS_CH20 #0
PB5	BUSAY BUSBX LCD_SEG22 / LCD_COM6	EBI_AD05 #1 EBI_ALE #3 EBI_A21 #0	WTIM0_CC2 #6 LE-TIM1_OUT0 #4 PCNT0_S0IN #6	ETH_TSUEXTCLK #0 US0_RTS #4 US2_CLK #1 QSPI0_DQ6 #1 LEU1_RX #4	PRS_CH21 #0
PB6	BUSBY BUSAX LCD_SEG23 / LCD_COM7	EBI_AD06 #1 EBI_WEn #3 EBI_A22 #0	TIM0_CC0 #3 TIM2_CC0 #4 WTIM3_CC0 #6 LE-TIM1_OUT1 #4 PCNT0_S1IN #6	ETH_TSUTMRTOG #0 US0_CTS #4 US2_CS #1 QSPI0_DQ7 #1	PRS_CH12 #1
PD5	BUSADC0Y BUSADC0X OPA2_OUT	EBI_A09 #1 EBI_A18 #3	TIM6_CC1 #7 WTIM0_CDTI1 #4 WTIM1_CC3 #1 WTIM2_CC2 #5	US1_RTS #1 U0_CTS #5 LEU0_RX #0 I2C1_SCL #3	PRS_CH11 #2 ETM_TD3 #0 ETM_TD3 #2

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
SDIO_DAT7	0: PD9 1: PB4		SDIO Data 7.
SDIO_WP	0: PF9 1: PC5 2: PB15 3: PB9		SDIO Write Protect.
TIM0_CC0	0: PA0 1: PF6 2: PD1 3: PB6	4: PF0 5: PC4 6: PA8 7: PA1	Timer 0 Capture Compare input / output channel 0.
TIM0_CC1	0: PA1 1: PF7 2: PD2 3: PC0	4: PF1 5: PC5 6: PA9 7: PA0	Timer 0 Capture Compare input / output channel 1.
TIM0_CC2	0: PA2 1: PF8 2: PD3 3: PC1	4: PF2 5: PA7 6: PA10 7: PA13	Timer 0 Capture Compare input / output channel 2.
TIM0_CDTI0	0: PA3 1: PC13 2: PF3 3: PC2	4: PB7	Timer 0 Complimentary Dead Time Insertion channel 0.
TIM0_CDTI1	0: PA4 1: PC14 2: PF4 3: PC3	4: PB8	Timer 0 Complimentary Dead Time Insertion channel 1.
TIM0_CDTI2	0: PA5 1: PC15 2: PF5 3: PC4	4: PB11	Timer 0 Complimentary Dead Time Insertion channel 2.
TIM1_CC0	0: PC13 1: PE10 2: PB0 3: PB7	4: PD6 5: PF2 6: PF13 7: PI6	Timer 1 Capture Compare input / output channel 0.
TIM1_CC1	0: PC14 1: PE11 2: PB1 3: PB8	4: PD7 5: PF3 6: PF14 7: PI7	Timer 1 Capture Compare input / output channel 1.
TIM1_CC2	0: PC15 1: PE12 2: PB2 3: PB11	4: PC13 5: PF4 6: PF15 7: PI8	Timer 1 Capture Compare input / output channel 2.
TIM1_CC3	0: PC12 1: PE13 2: PB3 3: PB12	4: PC14 5: PF12 6: PF5 7: PI9	Timer 1 Capture Compare input / output channel 3.
TIM2_CC0	0: PA8 1: PA12 2: PC8 3: PF2	4: PB6 5: PC2 6: PG8 7: PG5	Timer 2 Capture Compare input / output channel 0.

Table 12.2. QFN64 PCB Land Pattern Dimensions

Dimension	Typ
C1	8.90
C2	8.90
E	0.50
X1	0.30
Y1	0.85
X2	7.30
Y2	7.30

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05mm.
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
6. The stencil thickness should be 0.125 mm (5 mils).
7. The ratio of stencil aperture to land pad size can be 1:1 for all pads.
8. A 3x3 array of 1.45 mm square openings on a 2.00 mm pitch can be used for the center ground pad.
9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.